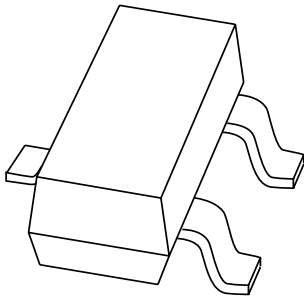


# DATA SHEET



## **BAT720** Schottky barrier diode

Product data sheet  
Supersedes data of 1999 May 26

2003 Mar 25

# Schottky barrier diode

# BAT720

### FEATURES

- Ultra high switching speed
- Low forward voltage
- Guard ring protected
- Small plastic SMD package.

### APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- Protection circuits.

### DESCRIPTION

Planar Schottky barrier diode with an integrated guard ring for stress protection in a small SOT23 plastic SMD package.

### MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BAT720	L6*

### Note

- \* = p : Made in Hong Kong.  
 \* = t : Made in Malaysia.  
 \* = W : Made in China.

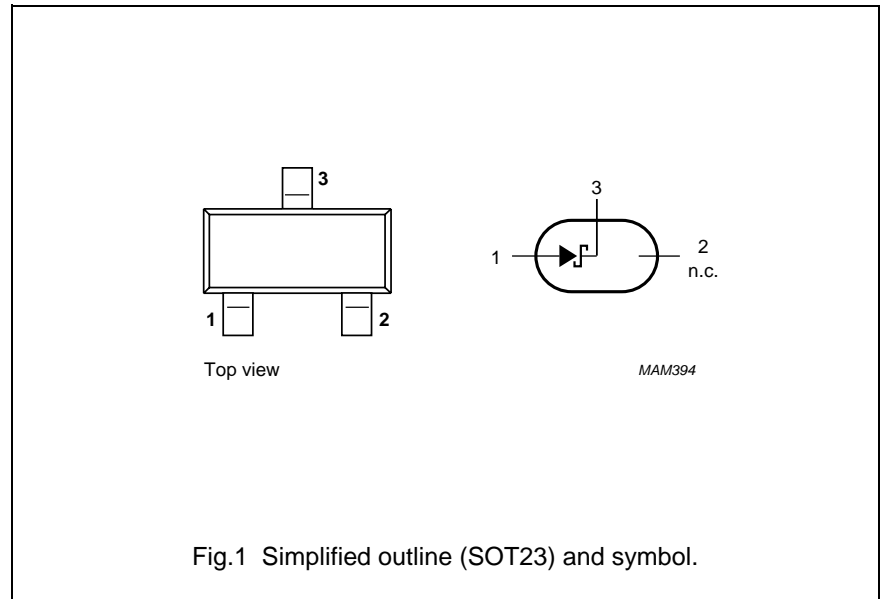
### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_R$	continuous reverse voltage		–	40	V
$I_F$	continuous forward current		–	500	mA
$I_{FSM}$	non-repetitive peak forward current	$t_p < 10$ ms	–	2	A
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	125	°C

### PINNING

PIN	DESCRIPTION
1	anode
2	not connected
3	cathode



## Schottky barrier diode

BAT720

**ELECTRICAL CHARACTERISTICS** $T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage	$I_F = 500\text{ mA}$ ; see Fig.2	–	550	mV
$I_R$	reverse current	$V_R = 35\text{ V}$ ; see Fig.3	–	100	$\mu\text{A}$
		$V_R = 35\text{ V}$ ; $T_j = 100\text{ °C}$ ; see Fig.3	–	10	mA
$C_d$	diode capacitance	$f = 1\text{ MHz}$ ; $V_R = 0$ ; see Fig.4	60	90	pF

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	500	K/W

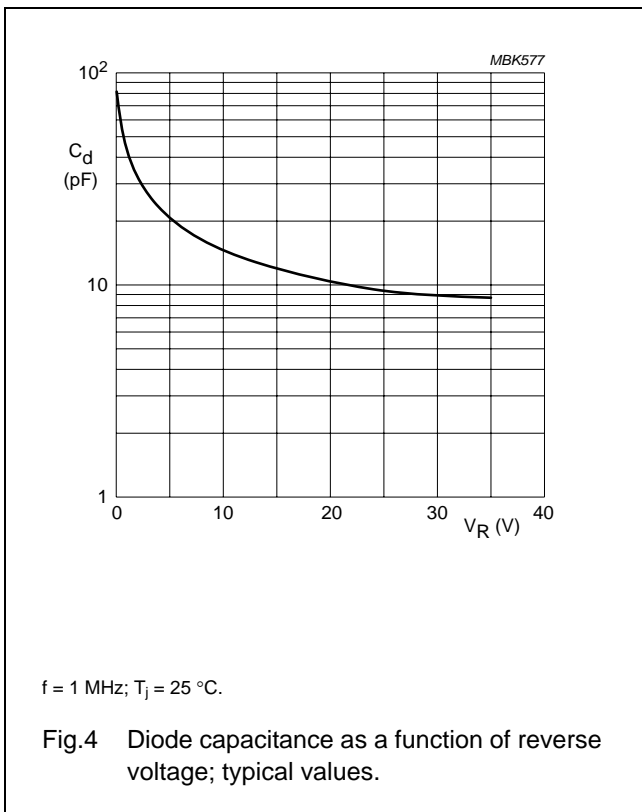
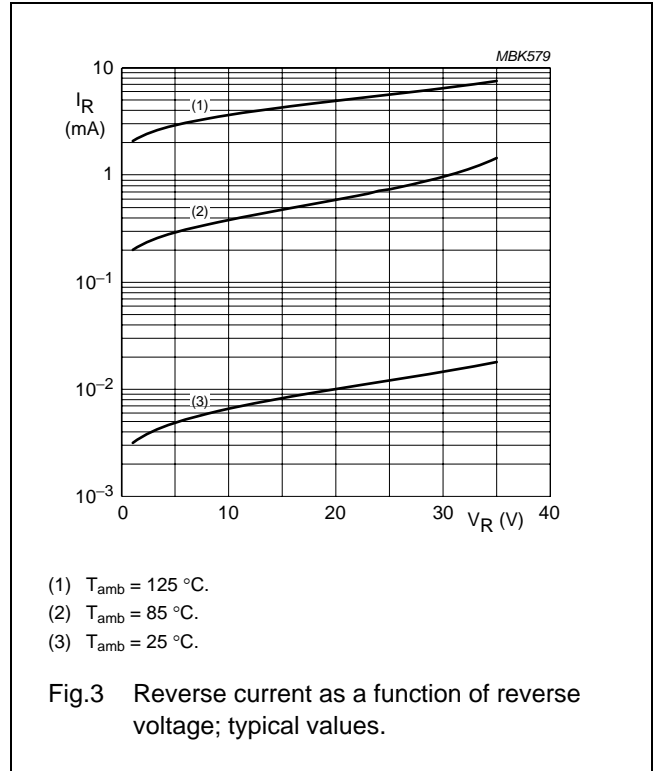
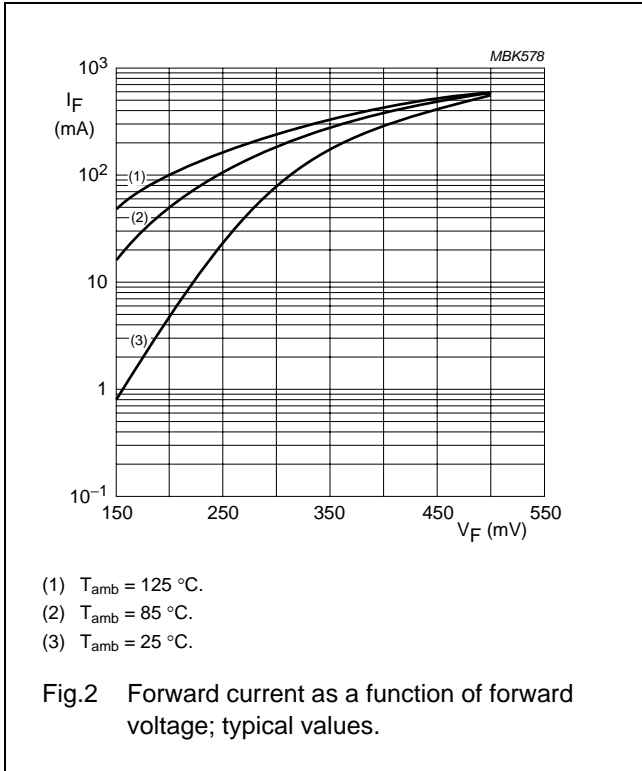
**Note**

1. Refer to SOT23 standard mounting conditions.

# Schottky barrier diode

# BAT720

## GRAPHICAL DATA



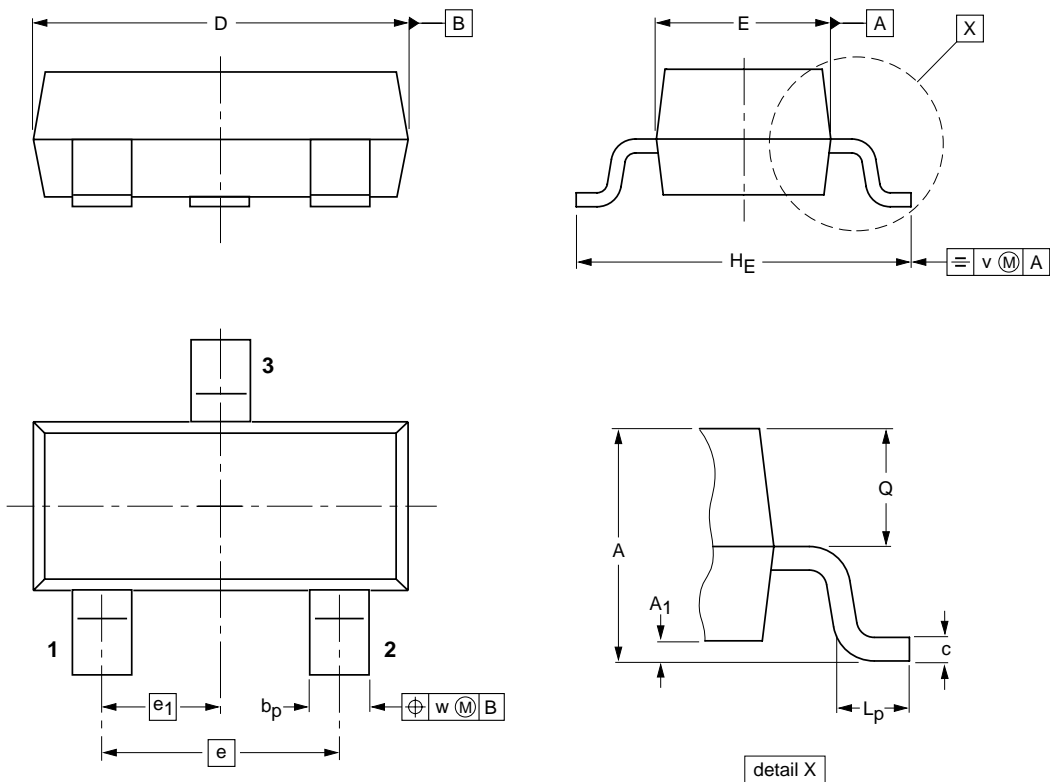
# Schottky barrier diode

# BAT720

## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



**DIMENSIONS (mm are the original dimensions)**

UNIT	A	A <sub>1</sub> max.	b <sub>p</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT23		TO-236AB			97-02-28 99-09-13

## Schottky barrier diode

BAT720

## DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

## **Contact information**

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